

74ALVCH16245

Low-Voltage 16-Bit Transceiver with Bus Hold 1.8/2.5/3.3 V

(3-State, Non-Inverting)

The 74ALVCH16245 is an advanced performance, non-inverting 16-bit transceiver. It is designed for very high-speed, very low-power operation in 1.8 V, 2.5 V or 3.3 V systems.

The 74ALVCH16245 is designed with byte control. It can be operated as two separate octals, or with the controls tied together, as a 16-bit wide function. The Transmit/Receive (T/Rn) inputs determine the direction of data flow through the bi-directional transceiver. Transmit (active-HIGH) enables data from A ports to B ports; Receive (active-LOW) enables data from B to A ports. The Output Enable inputs (OEn), when HIGH, disable both A and B ports by placing them in a HIGH Z condition. The data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating inputs at a valid logic state.

- Designed for Low Voltage Operation: $V_{CC} = 1.65 - 3.6 \text{ V}$
- 3.6 V Tolerant Inputs and Outputs
- High Speed Operation: 3.0 ns max for 3.0 to 3.6 V
3.7 ns max for 2.3 to 2.7 V
6.0 ns max for 1.65 to 1.95 V
- Static Drive: $\pm 24 \text{ mA}$ Drive at 3.0 V
 $\pm 12 \text{ mA}$ Drive at 2.3 V
 $\pm 4 \text{ mA}$ Drive at 1.65 V
- Supports Live Insertion and Withdrawal
- Includes Active Bushold to Hold Unused or Floating Inputs at a Valid Logic State
- I_{OFF} Specification Guarantees High Impedance When $V_{CC} = 0 \text{ V}^\dagger$
- Near Zero Static Supply Current in All Three Logic States (40 μA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds $\pm 250 \text{ mA}$ @ 125°C
- ESD Performance: Human Body Model >2000V; Machine Model >200V
- Second Source to Industry Standard 74ALVCH16245

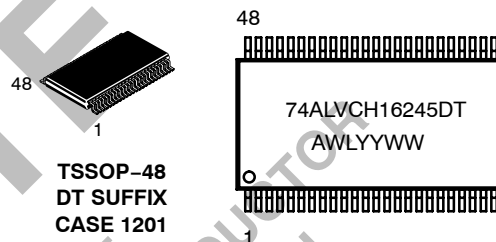
† To ensure the outputs activate in the 3-state condition, the output enable pins should be connected to V_{CC} through a pull-up resistor. The value of the resistor is determined by the current sinking capability of the output connected to the OE pin.



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MARKING DIAGRAM



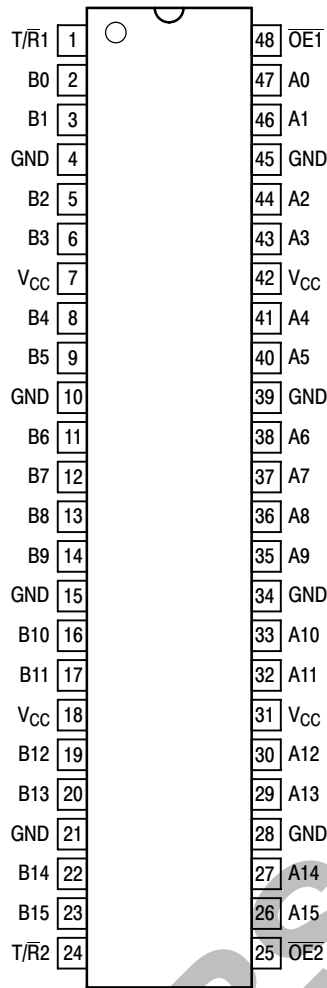
TSSOP-48
DT SUFFIX
CASE 1201

A = Assembly
Location
WL = Wafer Lot
YY = Year
WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping
74ALVCH16245DTR	TSSOP	2500/Tape & Reel

74ALVCH16245



**Figure 1. 48-Lead Pinout
(Top View)**

PIN NAMES

Pins	Function
$\overline{OE}n$	Output Enable Inputs
T/Rn	Transmit/Receive Inputs
A0–A15	Side A Inputs or 3-State Outputs
B0–B15	Side B Inputs or 3-State Outputs

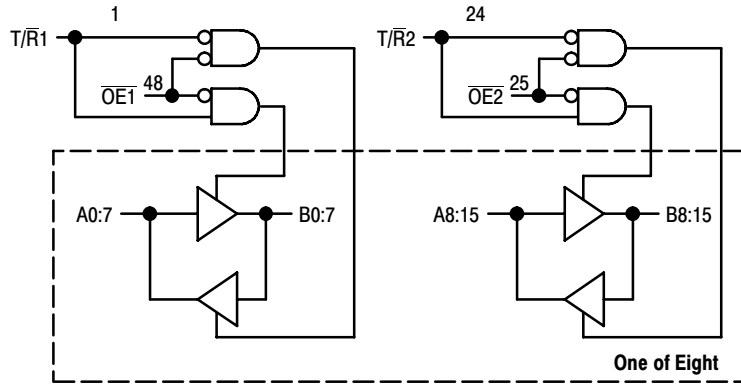


Figure 2. Logic Diagram

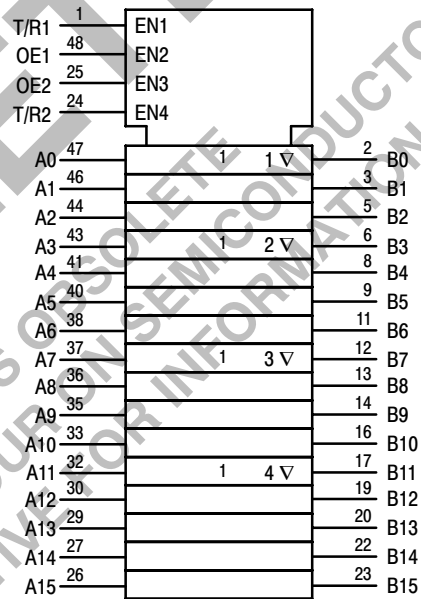


Figure 3. IEC Logic Diagram

Inputs		Outputs	Inputs		Outputs
OE1	T/R1		OE2	T/R2	
L	L	Bus B0:7 Data to Bus A0:7	L	L	Bus B8:15 Data to Bus A8:15
L	H	Bus A0:7 Data to Bus B0:7	L	H	Bus A8:15 Data to Bus B8:15
H	X	High Z State on A0:7, B0:7	H	X	High Z State on A8:15, B8:15

H = High Voltage Level; L = Low Voltage Level; X = High or Low Voltage Level and Transitions Are Acceptable

MAXIMUM RATINGS (Note 1)

Symbol	Parameter	Value	Unit
V_{CC}	DC Supply Voltage	– 0.5 to + 4.6	V
V_I	DC Input Voltage	– 0.5 to + 4.6	V
V_O	DC Output Voltage	– 0.5 to + 4.6	V
I_{IK}	DC Input Diode Current $V_I < GND$	– 50	mA
I_{OK}	DC Output Diode Current $V_O < GND$	– 50	mA
I_O	DC Output Sink Current	± 50	mA
I_{CC}	DC Supply Current per Supply Pin	± 100	mA
I_{GND}	DC Ground Current per Ground Pin	± 100	mA
T_{STG}	Storage Temperature Range	– 65 to + 150	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
T_J	Junction Temperature Under Bias	+ 150	°C
θ_{JA}	Thermal Resistance (Note 2)	90	°C/W
MSL	Moisture Sensitivity	Level 1	
F_R	Flammability Rating Oxygen Index: 30 to 35	UL 94 V–O @ 0.125 in	
V_{ESD}	ESD Withstand Voltage Human Body Model (Note 3) Machine Model (Note 4) Charged Device Model (Note 5)	> 2000 > 200 N/A	V
$I_{LATCH-UP}$	Latch-Up Performance Above V_{CC} and Below GND at 125°C (Note 6)	± 250	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. I_O absolute maximum rating must be observed.
2. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.
3. Tested to EIA/JESD22–A114–A.
4. Tested to EIA/JESD22–A115–A.
5. Tested to JESD22–C101–A.
6. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V_{CC}	Supply Voltage Operating Data Retention Only	2.3 1.5	3.6 3.6	V
V_I	Input Voltage (Note 7)	–0.5	3.6	V
V_O	Output Voltage (Active State) (3–State)	0 0	V_{CC} 3.6	V
T_A	Operating Free–Air Temperature	– 40	+ 85	°C
$\Delta t/\Delta V$	Input Transition Rise or Fall Rate $V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$ $V_{CC} = 3.0\text{ V} \pm 0.3\text{ V}$	0 0	20 10	ns/V

7. Unused inputs may not be left open. All inputs must be tied to a high–logic voltage level or a low–logic input voltage level.

DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Condition	T _A = -40°C to +85°C		Unit
			Min	Max	
V _{IH}	HIGH Level Input Voltage (Note 8)	1.65 V ≤ V _{CC} < 2.3 V	0.65 × V _{CC}		V
		2.3 V ≤ V _{CC} ≤ 2.7 V	1.7		
		2.7 V < V _{CC} ≤ 3.6 V	2.0		
V _{IL}	LOW Level Input Voltage (Note 8)	1.65 V ≤ V _{CC} < 2.3 V		0.35 × V _{CC}	V
		2.3 V ≤ V _{CC} ≤ 2.7 V		0.7	
		2.7 V < V _{CC} ≤ 3.6 V		0.8	
V _{OH}	HIGH Level Output Voltage	1.65 V ≤ V _{CC} ≤ 3.6 V; I _{OH} = -100 μA	V _{CC} - 0.2		V
		V _{CC} = 1.65 V; I _{OH} = -4 mA	1.2		
		V _{CC} = 2.3 V; I _{OH} = -6 mA	2.0		
		V _{CC} = 2.3 V; I _{OH} = -12 mA	1.7		
		V _{CC} = 2.7 V; I _{OH} = -12 mA	2.2		
		V _{CC} = 3.0 V; I _{OH} = -12 mA	2.4		
		V _{CC} = 3.0 V; I _{OH} = -24 mA	2.0		
V _{OL}	LOW Level Output Voltage	1.65 V ≤ V _{CC} ≤ 3.6 V; I _{OL} = 100 μA		0.2	V
		V _{CC} = 1.65 V; I _{OL} = 4 mA		0.45	
		V _{CC} = 2.3 V; I _{OL} = 6 mA		0.4	
		V _{CC} = 2.3 V; I _{OL} = 12 mA		0.7	
		V _{CC} = 2.7 V; I _{OL} = 12 mA		0.4	
		V _{CC} = 3.0 V; I _{OL} = 24 mA		0.55	
I _I	Input Leakage Current	1.65 V ≤ V _{CC} ≤ 3.6 V; 0 V ≤ V _I ≤ 3.6 V		± 5.0	μA
I _{I(HOLD)}	Minimum Bus-hold Input Current	V _{CC} = 3.6 V; V _{IN} = 0 to 3.6 V		± 500	μA
		V _{CC} = 3.0 V, V _{IN} = 0.8 V	75		
		V _{CC} = 3.0 V, V _{IN} = 2.0 V	-75		
		V _{CC} = 2.3 V, V _{IN} = 0.7 V	45		
		V _{CC} = 2.3 V, V _{IN} = 1.7 V	-45		
		V _{CC} = 1.65 V, V _{IN} = 0.58 V	25		
		V _{CC} = 1.65 V, V _{IN} = 1.07 V	-25		
I _{OZ}	3-State Output Current	1.65 V ≤ V _{CC} ≤ 3.6 V; 0 V ≤ V _O ≤ 3.6 V; V _I = V _{IH} or V _{IL}		± 10	μA
I _{OFF}	Power-Off Leakage Current	V _{CC} = 0 V; V _I or V _O = 3.6 V		10	μA
I _{CC}	Quiescent Supply Current (Note 9)	1.65 V ≤ V _{CC} ≤ 3.6 V; V _I = GND or V _{CC}		40	μA
		1.65 V ≤ V _{CC} ≤ 3.6 V; 3.6 V ≤ V _I , V _O ≤ 3.6 V		± 40	
ΔI _{CC}	Increase in I _{CC} per Input	2.7 V < V _{CC} ≤ 3.6 V; V _{IH} = V _{CC} - 0.6 V		750	μA

8. These values of V_I are used to test DC electrical characteristics only.

9. Outputs disabled or 3-state only.

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AC CHARACTERISTICS (Note 10; $t_R = t_F = 2.0$ ns; $C_L = 30$ pF; $R_L = 500$ Ω)

Symbol	Parameter	Waveform	Limits						Unit
			T _A = -40°C to +85°C						
			V _{CC} = 3.0 V to 3.6 V		V _{CC} = 2.3 V to 2.7 V		V _{CC} = 1.65 V to1.95 V		
			Min	Max	Min	Max	Min	Max	
t _{PLH} t _{PHL}	Propagation Delay Input to Output	1	1.0 1.0	3.0 3.0	1.0 1.0	3.7 3.7	1.0 1.0	6.0 6.0	ns
t _{PZH} t _{PZL}	Output Enable Time to High and Low Level	2	1.0 1.0	4.4 4.4	1.0 1.0	5.7 5.7	1.0 1.0	9.3 9.3	ns
t _{PHZ} t _{PLZ}	Output Disable Time From High and Low Level	2	1.0 1.0	4.1 4.1	1.0 1.0	5.2 5.2	1.0 1.0	7.6 7.6	ns
t _{OSHL} t _{OSLH}	Output-to-Output Skew (Note 11)			0.5 0.5		0.5 0.5		0.75 0.75	ns

10. For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

11. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}); parameter guaranteed by design.

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C_{IN}	Input Capacitance	Note 12	6	pF
C_{OUT}	Output Capacitance	Note 12	7	pF
C_{PD}	Power Dissipation Capacitance	Note 12, 10MHz	20	pF

12. $V_{CC} = 1.8, 2.5$ or 3.3 V; $V_I = 0$ V or V_{CC} .

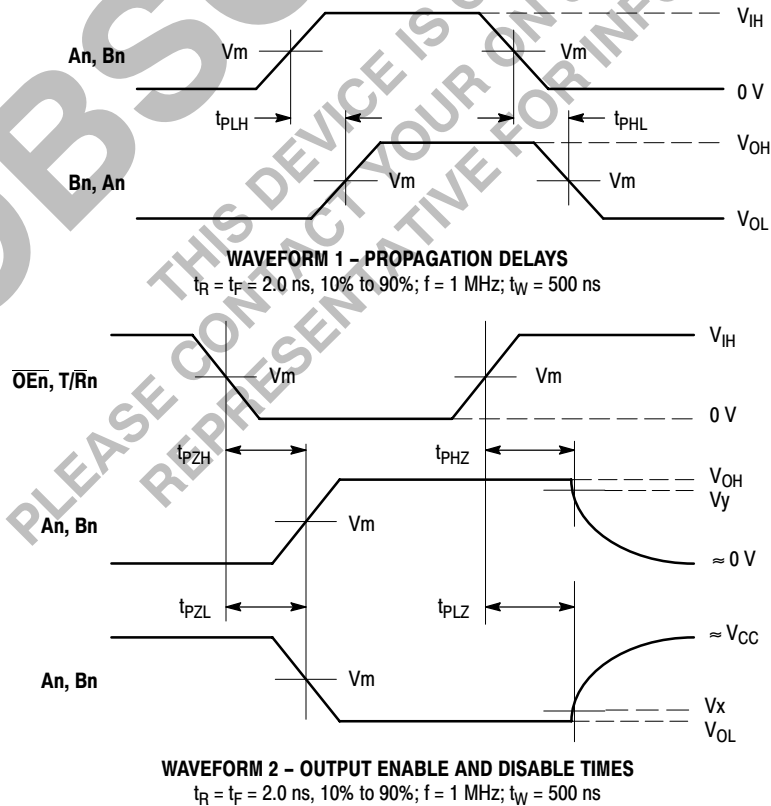
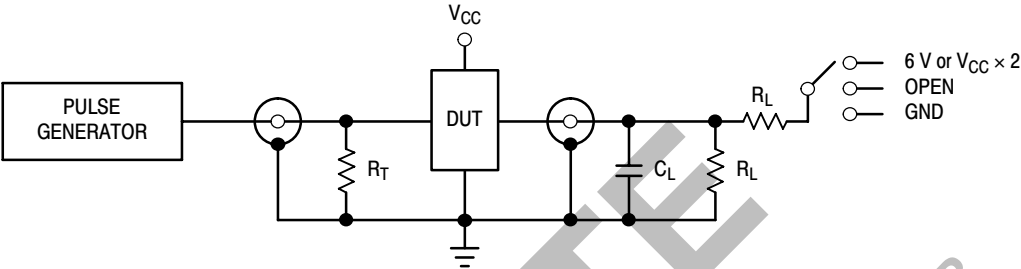


Figure 4. AC Waveforms

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Symbol	V _{CC}		
	3.3 V ±0.3 V	2.5 V ±0.2 V	1.8 V ±0.15 V
V _{IH}	2.7 V	V _{CC}	V _{CC}
V _m	1.5 V	V _{CC} /2	V _{CC} /2
V _x	V _{OL} + 0.3 V	V _{OL} + 0.15 V	V _{OL} + 0.15 V
V _y	V _{OH} - 0.3 V	V _{OH} - 0.15 V	V _{OH} - 0.15 V



TEST	SWITCH
t _{PLH} , t _{PHL}	Open
t _{PZL} , t _{PLZ}	6 V at V _{CC} = 3.3 ±0.3 V; V _{CC} × 2 at V _{CC} = 2.5 ±0.2 V; 1.8 V ±0.15 V
t _{PZH} , t _{PHZ}	GND

C_L = 50 pF for V_{CC} = 3.0 ± 0.3 V
R_L = 500 Ω or equivalent
R_T = Z_{OUT} of pulse generator (typically 50 Ω)

Figure 5. Test Circuit

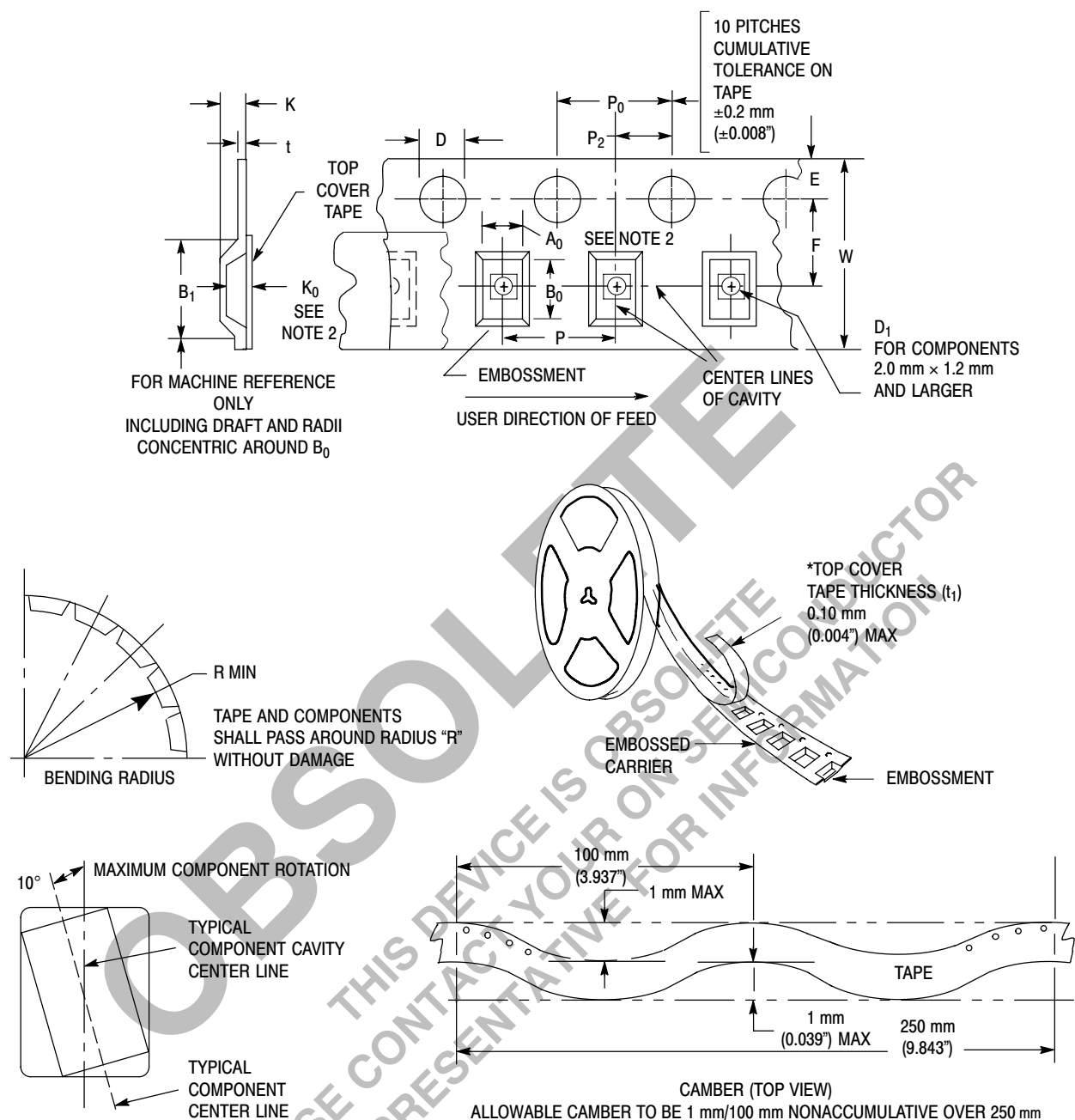


Figure 6. Carrier Tape Specifications

EMBOSSED CARRIER DIMENSIONS (See Notes 13 and 14)

Tape Size	B_1 Max	D	D_1	E	F	K	P	P_0	P_2	R	T	W
24mm	20.1mm (0.791")	1.5 + 0.1mm - 0.0 (0.059 +0.004" -0.0)	1.5mm Min (0.060")	1.75 ± 0.1 mm (0.069 ± 0.004 ")	11.5 ± 0.10 mm (0.453 ± 0.004 ")	11.9 mm Max (0.468")	16.0 ± 0.1 mm (0.63 ± 0.004 ")	4.0 ± 0.1 mm (0.157 ± 0.004 ")	2.0 ± 0.1 mm (0.079 ± 0.004 ")	30 mm (1.18")	0.6 mm (0.024")	24.3 mm (0.957")

13. Metric Dimensions Govern—English are in parentheses for reference only.

14. A_0 , B_0 , and K_0 are determined by component size. The clearance between the components and the cavity must be within 0.05 mm min to 0.50 mm max. The component cannot rotate more than 10° within the determined cavity.

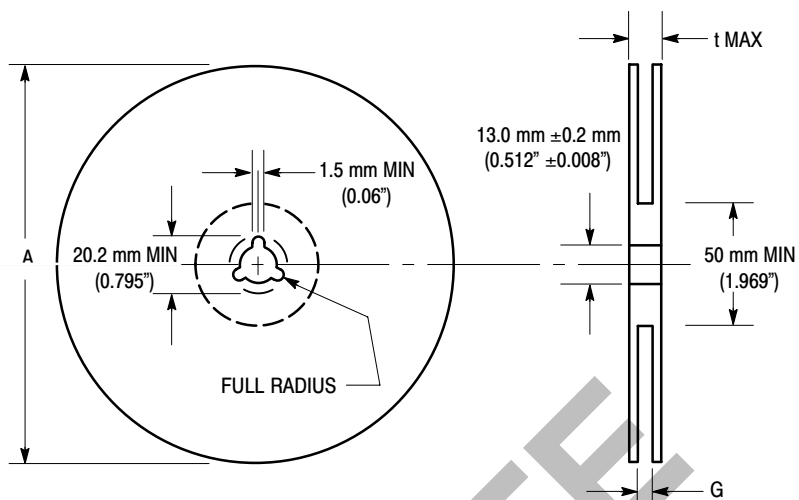


Figure 7. Reel Dimensions

REEL DIMENSIONS

Tape Size	A Max	G	t Max
24 mm	360 mm (14.173")	24.4 mm + 2.0 mm, -0.0 (0.961" + 0.078", -0.00)	30.4 mm (1.197")

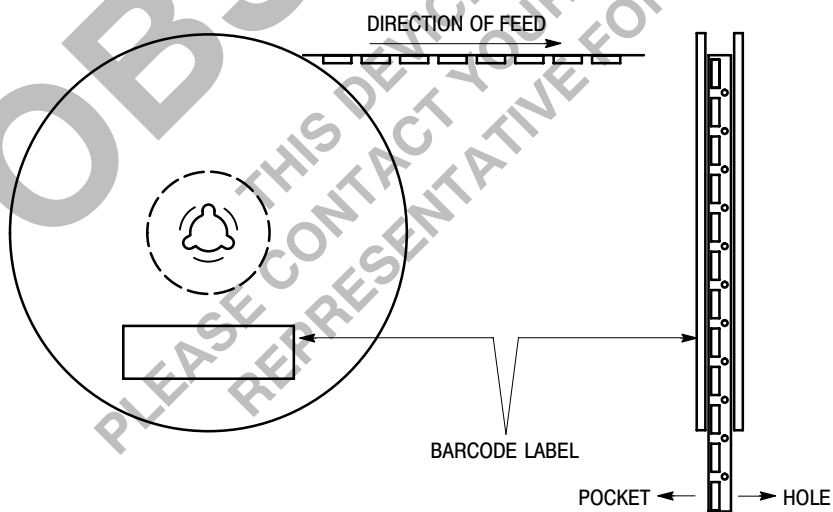


Figure 8. Reel Winding Direction

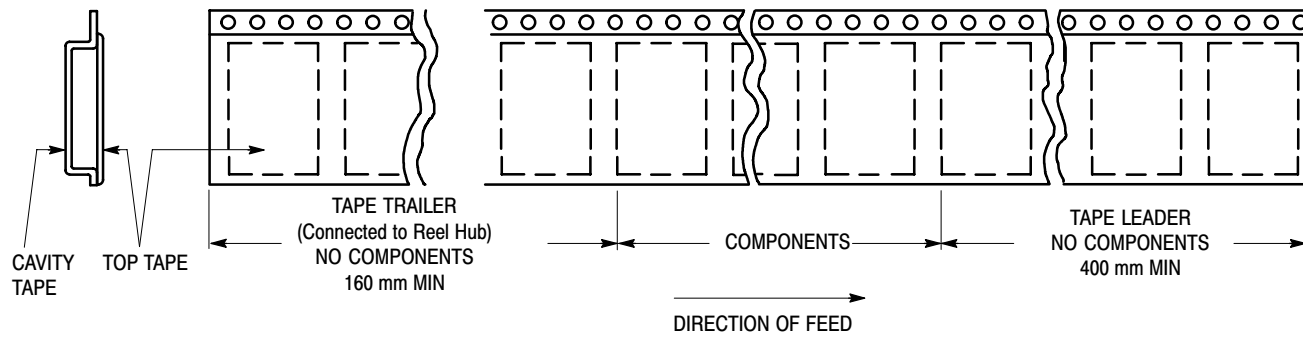


Figure 9. Tape Ends for Finished Goods

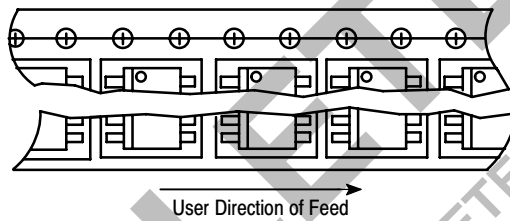


Figure 10. Reel Configuration

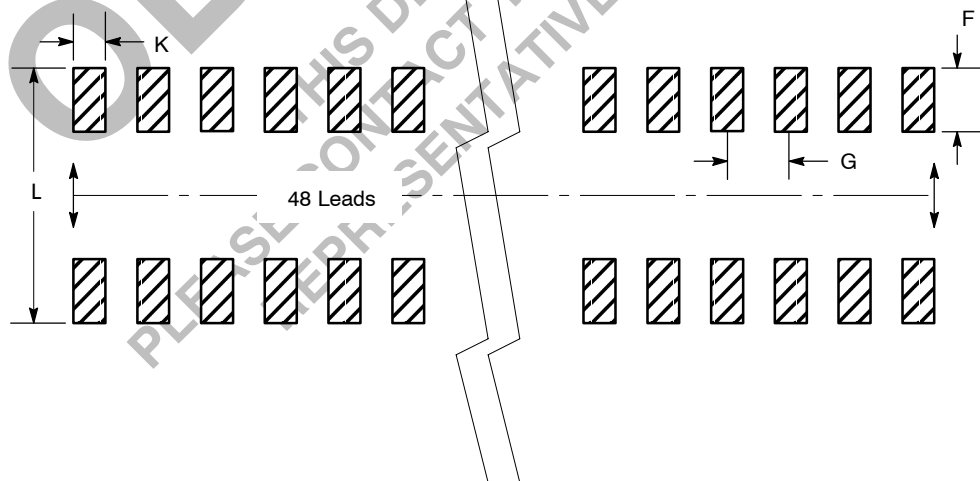


Figure 11. Package Footprint

